



## \*BIBDATASHEET\*

Bib Data Sheet

CONFIRMATION NO. 9453

SERIAL NUMBER 10/800,510	FILING DATE 03/15/2004  RULE	CLASS 257	GROUP ART UNIT 2818	ATTORNEY DOCKET NO. TSM03-0927
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## APPLICANTS

Tien-I Bao, Hsin-Chu, TAIWAN;

Syun-Ming Jang, Hsin-Chu, TAIWAN;

## \*\* CONTINUING DATA \*\*\*\*\*

This appln claims benefit of 60/547,697 02/25/2004 *TH*

## \*\* FOREIGN APPLICATIONS \*\*\*\*\*

*(None)*

## IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 06/02/2004

Foreign Priority claimed	<input type="checkbox"/> yes <input checked="" type="checkbox"/> no
35 USC 119 (a-d) conditions met	<input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance
Verified and Acknowledged	Examiner's Signature <i>TH</i> Initials

STATE OR

SHEETS

TOTAL

INDEPENDENT

COUNTRY  
TAIWANDRAWING  
4CLAIMS  
43CLAIMS  
5

## ADDRESS

43859  
SLATER & MATSIL, L.L.P.  
17950 PRESTON ROAD, SUITE 1000  
DALLAS, TX  
75252

## TITLE

Semiconductor device having a second level of metallization formed over a first level with minimal damage to the first level and method

FILING FEE

RECEIVED  
1356FEES: Authority has been given in Paper  
No. \_\_\_\_\_ to charge/credit DEPOSIT ACCOUNT  
No. \_\_\_\_\_ for following:☐ All Fees☐ 1.16 Fees ( Filing )☐ 1.17 Fees ( Processing Ext. of time )☐ 1.18 Fees ( Issue )☐ Other \_\_\_\_\_☐ Credit